Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Glass and metal **Overall Length:** 0.320 inches **Terminal Length:** 1.250 inches **Overall Diameter:** 0.380 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 65.0 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 20.00 amperes forward current, average nanoamperes **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 105.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0